



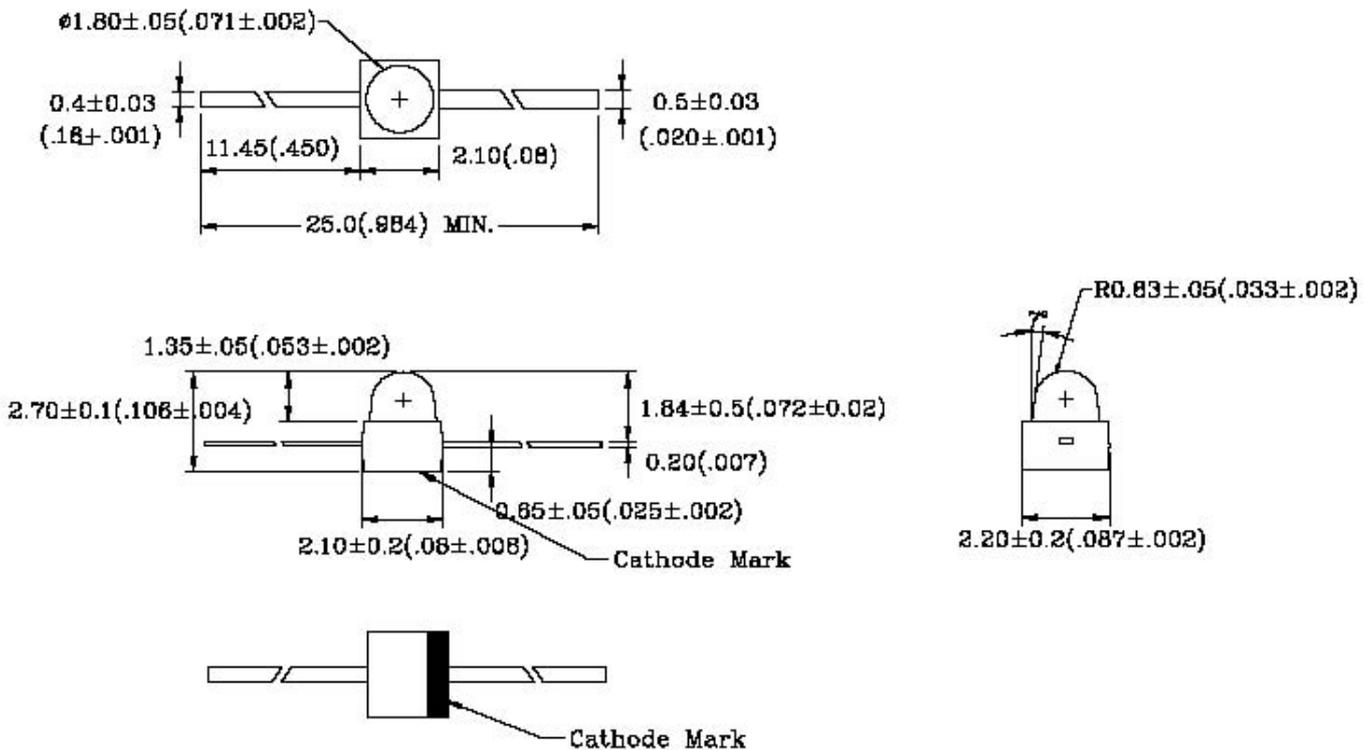
DIPTRONICS MANUFACTURING INC.

LED LAMPS SPECIFICATION

Axial Package LED Sheet

PAPT NO. : BG-S

● PACKAGE OUTLINE DIMENSIONS



Notes :

1. All dimensions are in millimeters.
2. Tolerance is $\pm 0.1\text{mm}$ (.004") unless otherwise noted.
3. Lead spacing measured where the leads emerge from the package.
4. Specifications are subject change without notice.



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● Chip Materials

- * Dice Material : AlGaInP
- * Light Color : Ultra Yellow Green
- * Lens Color : Water Clear

● Absolute Maximum Ratings (Ta = 25°C)

| Parameter | Symbol | Value | Unit |
|---|------------------|--------|------|
| Power Dissipation | Pd | 100 | mW |
| Peak Pulsing Current (1/8 Duty Cycle, f = 1kHz) | I _{fp} | 100 | mA |
| Forward Current | I _f | 30 | mA |
| Reverse Voltage | V _r | 5 | V |
| Operating Temperature Range | T _{opr} | -25~80 | °C |
| Storage Temperature Range | T _{stg} | -30~85 | °C |
| Lead Soldering Temperature | See Page 4 | | — |

● Electro-Optical Characteristics (Ta = 25°C)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-----------------------------|-------------------|----------------------|------|------|------|------|
| Wavelength at peak emission | λ _P | I _f =20mA | | 570 | | nm |
| Viewing Angle | 2θ _{1/2} | I _f =10mA | | 35 | | Deg. |
| Dominant Wavelength | λ _D | I _f =20mA | 566 | | 576 | nm |
| Spectral Line Half-Width | Δλ | I _f =20mA | | 30 | | nm |
| Forward Voltage | V _f | I _f =20mA | | 2.0 | 2.6 | V |
| Chip luminous intensity | I _v | I _f =20mA | 42 | 100 | | mcd |
| Reverse Current | I _r | V _r =5V | | | 100 | μA |



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● OPTICAL CHARACTERISITIC CURVES

Fig.1 Relative intensity vs. wavelength

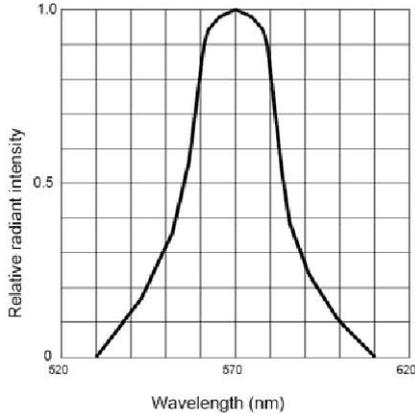


Fig.2 Forward current derating curve vs. ambient temperature

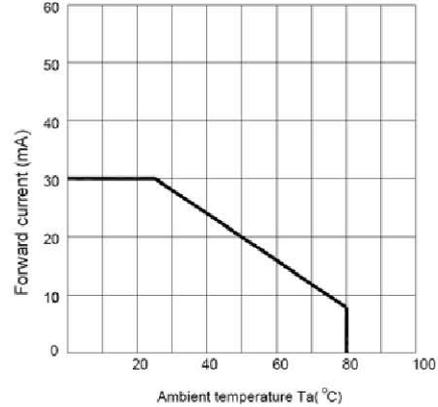


Fig.3 Forward current vs. forward voltage

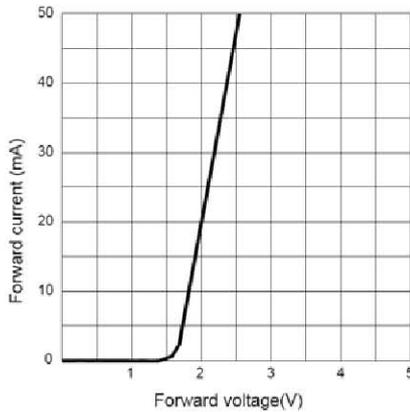


Fig.4 Relative luminous intensity vs. ambient temperature

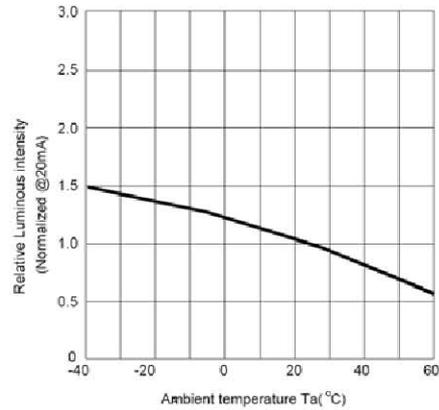


Fig.5 Relative luminous intensity vs. forward current

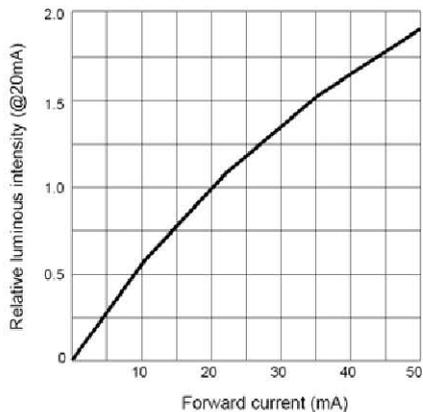
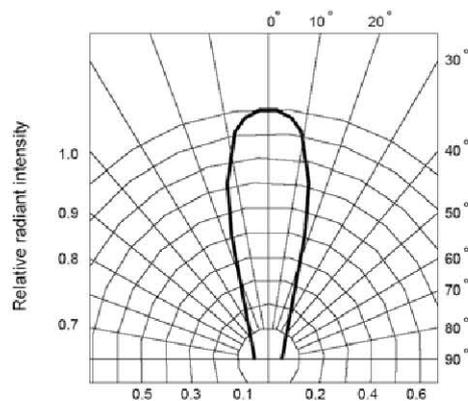


Fig.6 Radiation diagram





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LED LAMPS SPECIFICATION

● Soldering :

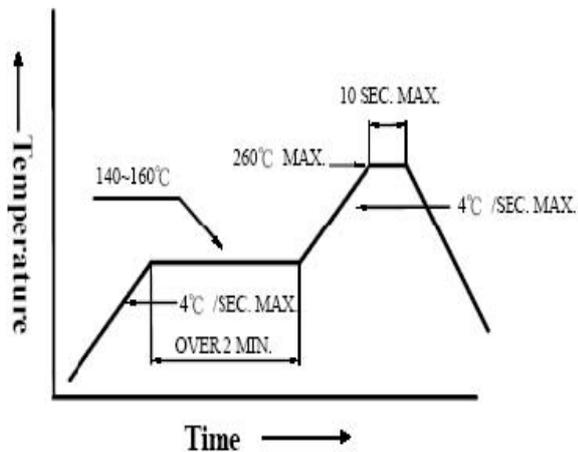
1. Manual Of Soldering :

The temperature of the iron tip should not be higher than 300°C (572°F) and soldering within 3 seconds per solder-land is to be observed.

2. Reflow soldering :

Preheating : $140^{\circ}\text{C} \sim 160^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 2 minutes.

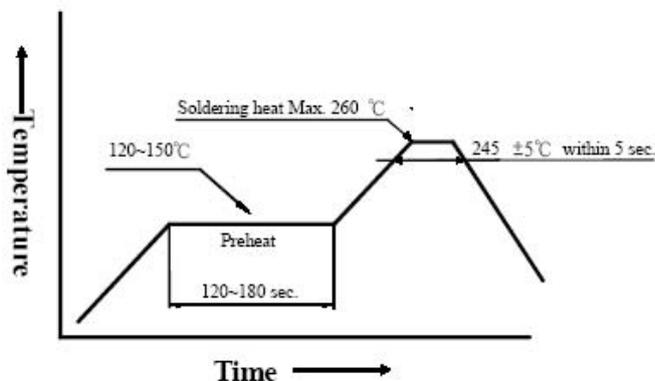
Operation heating : 260°C (Max) within 10 seconds.(Max)



3. DIP soldering(Wave Soldering) :

Preheating : $120^{\circ}\text{C} \sim 150^{\circ}\text{C}$, within 120~180sec

Operation heating : $245^{\circ}\text{C} \pm 5^{\circ}\text{C}$ within 5 sec 260°C (Max).





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● **Handing :**

Care must be taken not to cause to the epoxy resin portion of LEDs while it is exposed to high temperature.

Care must be taken not rub the epoxy resin portion of LEDs with hard or sharp article such as the sand blast and the metal hook.

● **Notes for designing :**

Care must be taken to provide the current limiting resistor in the circuit so as drive the LEDs within the rated figures. Also, caution should be taken not to overload LEDs with instantaneous voltage ate the turning ON and OFF of the circuit.

When using the pulse drive care must be taken to keep the average current within the rated figures. Also, the circuit should be designed so as subjected to reverse voltage when turning off the LEDs.

● **Storage :**

In order to avoid the absorption of moisture, it is recommended to solder LEDs as soon as possible after unpacking the sealed envelop.

If the envelope is still packed, to store it in the environment as following :

(1) Temperature : 5°C - 30°C (41°F) Humidity : RH 60% Max.

(2) After this bag is opened, devices that will be applied to infared reflow, vapor-phase reflow, or equivalent soldering process must be :

a. Completed within 24 hours

b. Stored at less than 30%RH

(3) Devices require baking before mounting, if (2) a or (2) b is not met

(4) If baking is required, devices must be baked under below conditions

12 hours at $60^{\circ}\text{C} \pm 3^{\circ}\text{C}$



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● OPTICAL CHATACTERISTIC CURVES

| Classification | Test Item | Reference Standard | Test Conditions | Result |
|--------------------|--|--|--|--------|
| Endurance Test | Operation Life | MIL-STD-750 : 1026 MIL-STD-883 : 1005 JIS C 7021 : B-1 | Connect with a power $I_f=20\text{mA}$ T_a =Under room temperature Test time=1,000hrs | 0/20 |
| | High Temperature High Humidity Storage | MIL-STD-202 : 103B JIS C 7021 : B-11 | $T_a=+65^\circ\text{C}\pm 5^\circ\text{C}$ RH=90%~95% Test time=240hrs | 0/20 |
| | High Temperature Storage | MIL-STD-883 : 1008 JIS C 7021 : B-10 | High $T_a=+85^\circ\text{C}\pm 5^\circ\text{C}$ Test time=1,000hrs | 0/20 |
| | Low Temperature Storage | JIS C 7021 : B-12 | Low $T_a=-35^\circ\text{C}\pm 5^\circ\text{C}$ Test time=1,000hrs | 0/20 |
| Environmental Test | Temperature Cycling | MIL-STD-202 : 107D MIL-STD-705 : 1051 MIL-STD-883 : 1010 JIS C 7021 : A-4 | $-35^\circ\text{C} \rightarrow +25^\circ\text{C} \rightarrow +85^\circ\text{C} \rightarrow +25^\circ\text{C}$ 60min-20min- 60min-20min Test Time=5 cycle | 0/20 |
| | Thermal Shock | MIL-STD-202 : 107D MIL-STD-705 : 1051 MIL-STD-883 : 1011 | $-35^\circ\text{C}\pm 5^\circ\text{C} \sim +85^\circ\text{C}\pm 5^\circ\text{C}$ 20min 20min Test Time=10 cycle | 0/20 |
| | Solder Resistance | MIL-STD-202 : 201A MIL-STD-750 : 2031 JIS C 7021 : A-1 | Preheating : $140^\circ\text{C} \sim 160^\circ\text{C}$, within 2 minutes. Operation heating : 235°C (Max.), within 10seconds.(Max.) | 0/20 |

JUDGMENT CRITERIA OF FAILURE FOR THE RELIABILITY

| Measuring items | Symbol | Measuring conditions | Judgement criteria for failure |
|--------------------|--------------------|----------------------|--------------------------------|
| Forward voltage | $V_F(V)$ | $I_f=20\text{mA}$ | Over $U \times 1.2$ |
| Reverse current | $I_r(\mu\text{A})$ | $V_r=5\text{V}$ | Over $U \times 2$ |
| Luminous intensity | $I_v(\text{mcd})$ | $I_f=20\text{mA}$ | Below $S \times 0.5$ |

Note :

1. U means the upper limit of specified characteristics. S means initial value.
2. Measurement shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.